PIN 3

# onsemi

# **Digital Transistors (BRT) R1 = 2.2 k\Omega, R2 = 47 k\Omega**

NPN Transistors with Monolithic Bias Resistor Network

# MUN2235, MMUN2235L, MUN5235, DTC123JE, DTC123JM3, NSBC123JF3

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

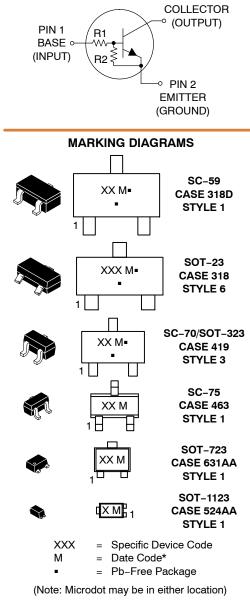
## Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Rating	Symbol	Max	Unit			
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc			
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc			
Collector Current – Continuous	۱ <sub>C</sub>	100	mAdc			
Input Forward Voltage	V <sub>IN(fwd)</sub>	12	Vdc			
Input Reverse Voltage	V <sub>IN(rev)</sub>	6	Vdc			

MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



**PIN CONNECTIONS** 

\*Date Code orientation may vary depending upon manufacturing location.

## **ORDERING INFORMATION**

See detailed ordering, marking, and shipping information on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

### Table 1. ORDERING INFORMATION

Device	Part Marking	Package	Shipping <sup>†</sup>
MUN2235T1G	6M	SC–59 (Pb–Free)	3000 / Tape & Reel
MMUN2235LT1G, NSVMMUN2235LT1G*	AA2	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5235T1G, SMUN5235T1G*	8M	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTC123JET1G, NSVDTC123JET1G*	8M	SC–75 (Pb–Free)	3000 / Tape & Reel
DTC123JM3T5G, NSVDTC123JM3T5G*	8M	SOT-723 (Pb-Free)	8000 / Tape & Reel

#### DISCONTINUED (Note 1)

NSBC123JF3T5G	V	SOT-1123	8000 / Tape & Reel
		(Pb-Free)	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

1. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on <u>www.onsemi.com</u>.

(1) SC-75 and SC-70/SOT323; Minimum Pad

(4) SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace

(2) SC–59; Minimum Pad (3) SOT–23; Minimum Pad

(5) SOT-723; Minimum Pad

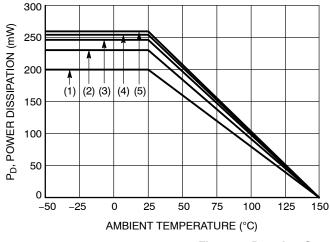


Figure 1. Derating Curve

### Table 2. THERMAL CHARACTERISTICS

	Characteristic	Symbol	Мах	Unit
THERMAL CHARACTERI	STICS (SC-59) (MUN2235)			
Total Device Dissipation		PD		
T <sub>A</sub> = 25°C	(Note 2)		230	mW
	(Note 3)		338	
Derate above 25°C	(Note 2)		1.8	mW/°C
	(Note 3)		2.7	
Thermal Resistance,	(Note 2)	$R_{ extsf{ heta}JA}$	540	°C/W
Junction to Ambient	(Note 3)		370	
Thermal Resistance,	(Note 2)	R <sub>θJL</sub>	264	°C/W
Junction to Lead	(Note 3)		287	
Junction and Storage Tem	perature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C
THERMAL CHARACTERI	STICS (SOT-23) (MMUN2235L)			
Total Device Dissipation		PD		
$T_A = 25^{\circ}C$	(Note 2)		246	mW
	Note 3)		400	
Derate above 25°C	(Note 2)		2.0	mW/°C
	(Note 3)		3.2	
Thermal Resistance,	(Note 1)	R <sub>θJA</sub>	508	°C/W
Junction to Ambient	(Note 3)		311	
Thermal Resistance,	(Note 2)	$R_{ ext{ heta}JL}$	174	°C/W
Junction to Lead	Note 3)	UUL UUL	208	,
Junction and Storage Tem	perature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C
THERMAL CHARACTERI	STICS (SC-70/SOT-323) (MUN5235)	Ŭ	1	
Total Device Dissipation		PD		
T <sub>A</sub> = 25°C	(Note 2)	b	202	mW
	(Note 3)		310	
Derate above 25°C	(Note 2)		1.6	mW/°C
	(Note 3)		2.5	
Thermal Resistance,	(Note 2)	R <sub>θJA</sub>	618	°C/W
Junction to Ambient	(Note 3)		403	
Thermal Resistance,	(Note 2)	$R_{ ext{ heta}JL}$	280	°C/W
Junction to Lead	(Note 3)	· •63L	332	0,11
Junction and Storage Tem	perature Range	T <sub>J</sub> , T <sub>stq</sub>	–55 to +150	°C
THERMAL CHARACTERI	STICS (SC-75) (DTC123JE)	0. 0.9		
Total Device Dissipation		PD		
$T_A = 25^{\circ}C$	(Note 2)		200	mW
	(Note 3)		300	
Derate above 25°C	(Note 2)		1.6	mW/°C
	(Note 3)		2.4	
Thermal Resistance,	(Note 2)	$R_{ heta JA}$	600	°C/W
Junction to Ambient	(Note 3)	•	400	
Junction and Storage Tem	perature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERI	STICS (SOT-723) (DTC123JM3)			
		PD		
Total Device Dissipation	(Note 2)		260	mW
Total Device Dissipation T <sub>A</sub> = 25°C			600	
$T_A = 25^{\circ}C$	(Note 3)			
	(Note 3) (Note 2)		2.0	mW/°C
$T_A = 25^{\circ}C$	(Note 3)			
$T_A = 25^{\circ}C$ Derate above 25°C Thermal Resistance,	(Note 3) (Note 2)	R <sub>0JA</sub>	2.0	mW/°C °C/W
$T_A = 25^{\circ}C$	(Note 3) (Note 2) (Note 3)	R <sub>0JA</sub>	2.0 4.8	

#### **Table 2. THERMAL CHARACTERISTICS**

	Characteristic	Symbol	Мах	Unit
THERMAL CHARACTERI	STICS (SOT-1123) (NSBC123JF3)			
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 4) (Note 5) (Note 4) (Note 5)	PD	254 297 2.0 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 4) (Note 5)	$R_{ hetaJA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 4)	R <sub>θJL</sub>	193	°C/W
Junction and Storage Tem	perature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

2. FR-4 @ Minimum Pad.

3. FR-4 @ 1.0 x 1.0 Inch Pad.

FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

# Table 3. ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = $25^{\circ}$ C, unless otherwise noted)

Symbol	Min	Тур	Max	Unit
I <sub>CBO</sub>	_	-	100	nAdc
I <sub>CEO</sub>	-	-	500	nAdc
I <sub>EBO</sub>	-	-	0.2	mAdc
V <sub>(BR)CBO</sub>	50	-	-	Vdc
V <sub>(BR)CEO</sub>	50	_	-	Vdc
-	I <sub>CBO</sub> I <sub>CEO</sub> I <sub>EBO</sub> V <sub>(BR)CBO</sub>	I <sub>CB0</sub> – I <sub>CE0</sub> – I <sub>EB0</sub> – V <sub>(BR)CB0</sub> 50 V <sub>(BR)CE0</sub>	I <sub>CBO</sub> – – I <sub>CEO</sub> – – I <sub>EBO</sub> – – V <sub>(BR)CBO</sub> 50 – V <sub>(BR)CEO</sub>	ICBO     -     -     100       ICEO     -     -     500       IEBO     -     -     0.2       V(BR)CBO     50     -     -       V(BR)CEO     -     -     -

DC Current Gain (Note 5) ( $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$ )	h <sub>FE</sub>	80	140	-	
Collector – Emitter Saturation Voltage (Note 6) ( $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ )	V <sub>CE(sat)</sub>	-	_	0.25	Vdc
Input Voltage (off) (V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 100 μA)	V <sub>i(off)</sub>	-	0.6	0.5	Vdc
Input Voltage (on) (V <sub>CE</sub> = 0.3 V, I <sub>C</sub> = 5.0 mA)	V <sub>i(on)</sub>	1.1	0.8	-	Vdc
Output Voltage (on) ( $V_{CC}$ = 5.0 V, $V_B$ = 2.5 V, $R_L$ = 1.0 k $\Omega$ )	V <sub>OL</sub>	-	_	0.2	Vdc
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OH</sub>	4.9	_	_	Vdc
Input Resistor	R1	1.5	2.2	2.9	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	0.038	0.047	0.056	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 6. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .

TYPICAL CHARACTERISTICS MUN2235, MMUN2235L, MUN5235, DTC123JE, DTC123JM3

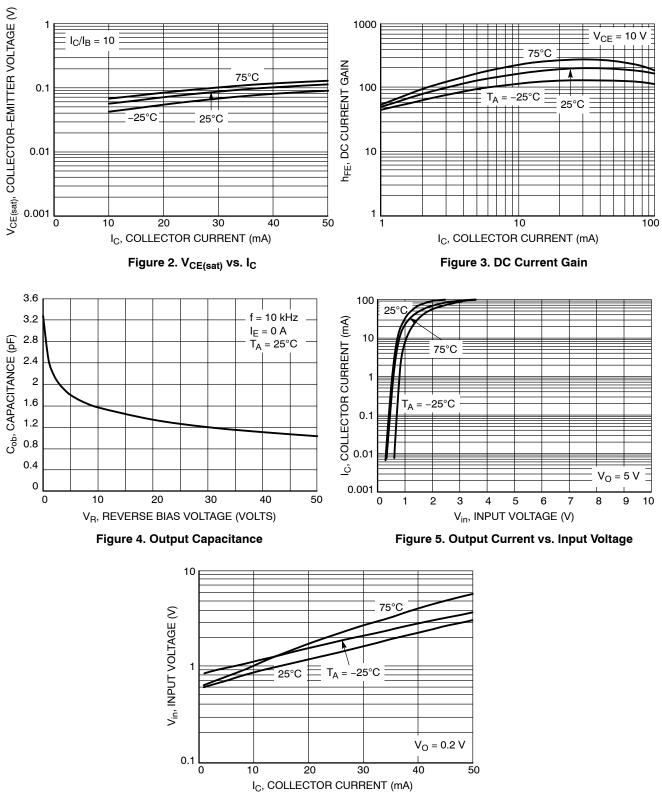
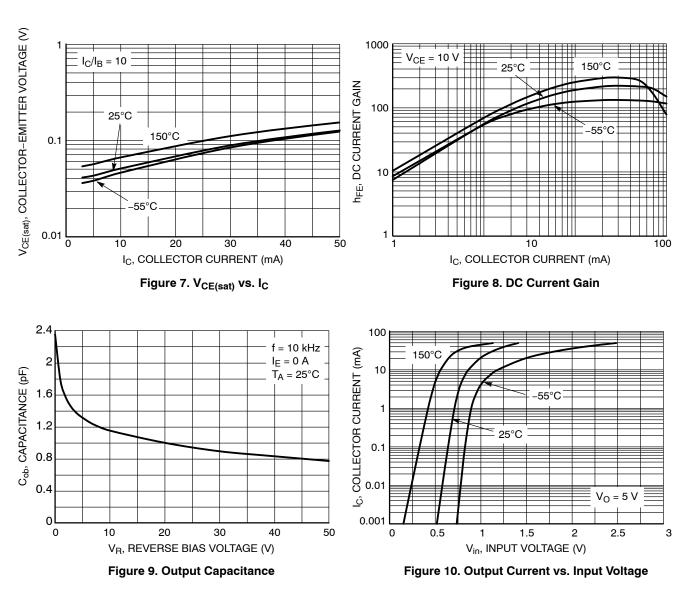
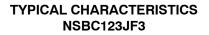
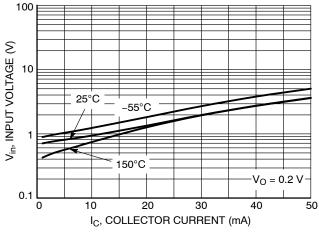


Figure 6. Input Voltage vs. Output Current

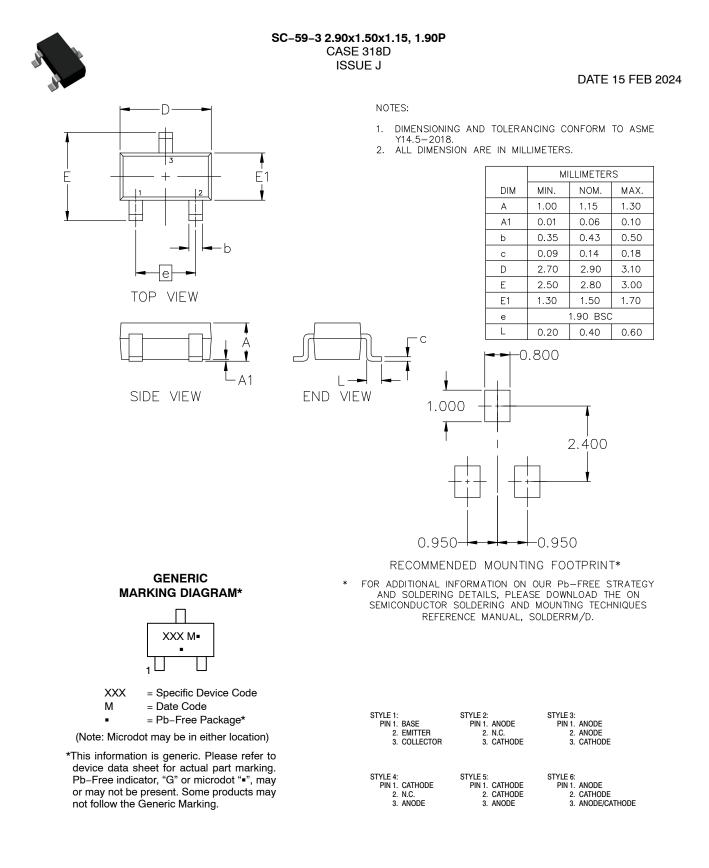








#### PACKAGE DIMENSIONS



# semi



#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024









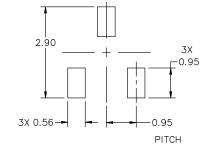




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS						
DIM	MIN	NOM	МАХ			
А	0.89	1.00	1.11			
A1	0.01	0.06	0.10			
b	0.37	0.44	0.50			
с	0.08	0.14	0.20			
D	2.80	2.90	3.04			
E	1.20	1.30	1.40			
е	1.78	1.90	2.04			
L	0.30	0.43	0.55			
L1	0.35	0.54	0.69			
Ηe	2.10	2.40	2.64			
Т	0°		10°			

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **STYLES ON PAGE 2**

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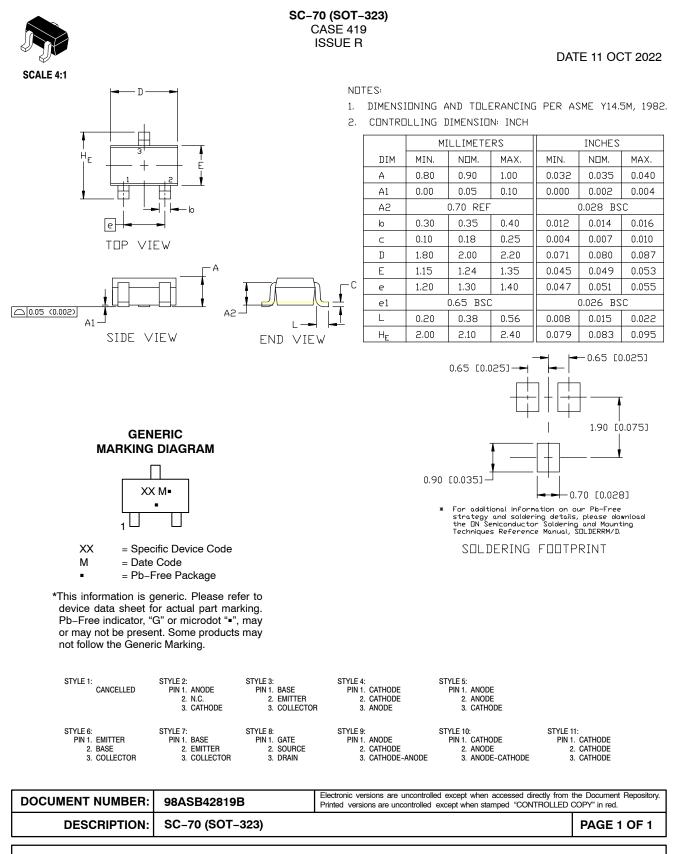
DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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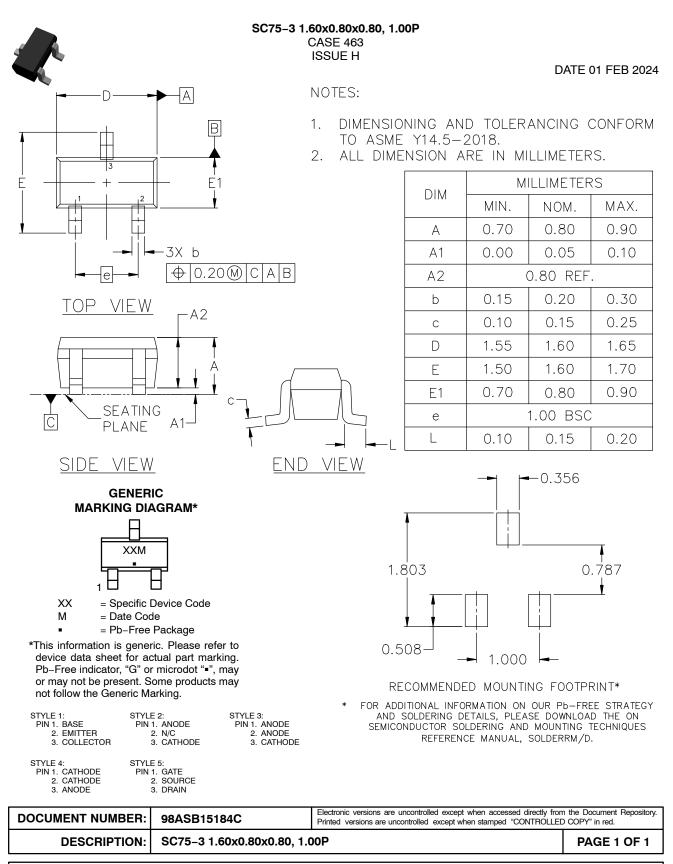
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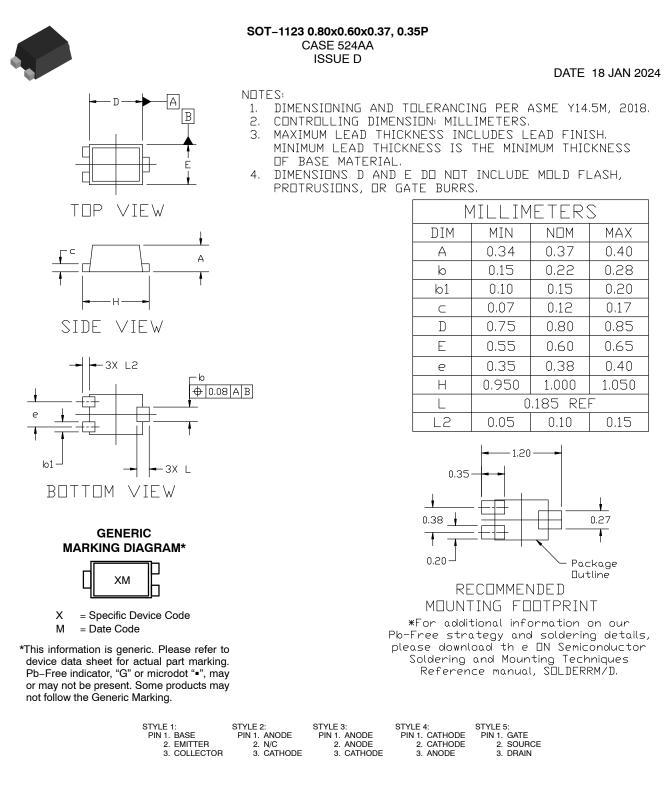
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DESCRIPTION:	SOT-1123 0.80x0.60x0.37, 0.35P		PAGE 1 OF 1

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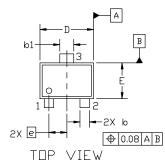


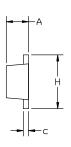
#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

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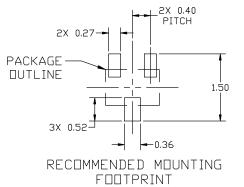
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- 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



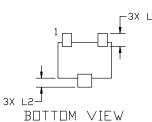


SIDE VIEW

		MILLIMETERS				
	DIM	MIN.	NDM.	MAX.		
1	А	0.45	0.50	0.55		
	b	0.15	0.21	0.27		
	b1	0.25	0.31	0.37		
	С	0.07	0.12	0.17		
	D	1.15	1.20	1.25		
	E	0.75	0.80	0.85		
	e	0.40 BSC				
	Н	1.15	1.20	1.25		
	L	0.29 REF				
	L2	0.15	0.20	0.25		



\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM\*** 



XX = Specific Device Code Μ = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

2. EMITTER 2.	II: STYLE 3: ANODE PIN 1. ANODE N/C 2. ANODE CATHODE 3. CATHODE	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN		
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DESCRIPTION:	SOT-723 1.20x0.80x	0.50, 0.40P			PAGE 1 OF 1

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Authorized Distributor

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